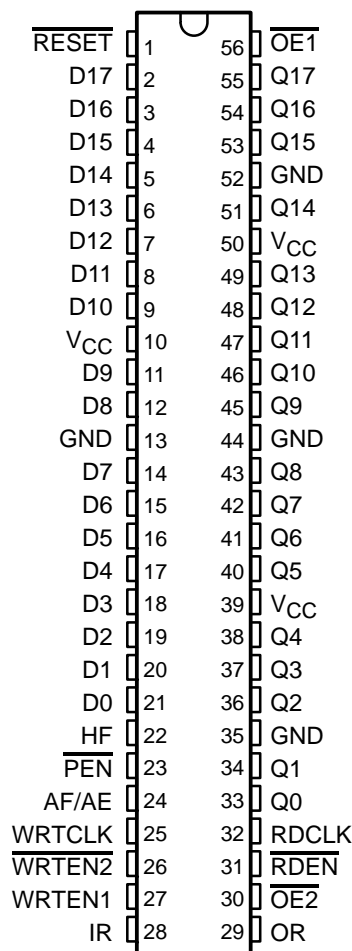


- Member of the Texas Instruments Widebus™ Family
- Free-Running Read and Write Clocks Can Be Asynchronous or Coincident
- Read and Write Operations Synchronized to Independent System Clocks
- Input-Ready Flag Synchronized to Write Clock
- Output-Ready Flag Synchronized to Read Clock
- 64 Words by 18 Bits
- Low-Power Advanced CMOS Technology
- Half-Full Flag and Programmable Almost-Full/Almost-Empty Flag
- Bidirectional Configuration and Width Expansion Without Additional Logic
- Fast Access Times of 12 ns With a 50-pF Load and All Data Outputs Switching Simultaneously
- Data Rates From 0 to 67 MHz
- Pin Compatible With SN74ACT7803 and SN74ACT7805
- Packaged in Shrink Small-Outline 300-mil Package (DL) Using 25-mil Center-to-Center Spacing

**DL PACKAGE
(TOP VIEW)**



description

The SN74ACT7813 is a 64-word × 18-bit FIFO suited for buffering asynchronous data paths at 67-MHz clock rates and 12-ns access times. Its 56-pin shrink small-outline package (DL) offers greatly reduced board space over DIP, PLCC, and conventional SOIC packages. Two devices can be configured for bidirectional data buffering without additional logic. Multiple distributed V_{CC} and GND pins along with TI's patented output edge control (OEC™) circuit dampen simultaneous switching noise.

The write clock (WRTCLK) and read clock (RDCLK) should be free running and can be asynchronous or coincident. Data is written to memory on the rising edge of WRTCLK when WRTEN1 is high, $\overline{WRTEN2}$ is low, and IR is high. Data is read from memory on the rising edge of RDCLK when \overline{RDEN} , $\overline{OE1}$, and $\overline{OE2}$ are low and OR is high. The first word written to memory is clocked through to the output buffer regardless of the \overline{RDEN} , $\overline{OE1}$, and $\overline{OE2}$ levels. The OR flag indicates that valid data is present on the output buffer.

The FIFO can be reset asynchronously to WRTCLK and RDCLK. \overline{RESET} must be asserted while at least four WRTCLK and four RDCLK rising edges occur to clear the synchronizing registers. Resetting the FIFO initializes the IR, OR, and HF flags low and the AF/AE flag high. The FIFO must be reset upon power up.

The SN74ACT7813 is characterized for operation from 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus and OEC are trademarks of Texas Instruments Incorporated.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

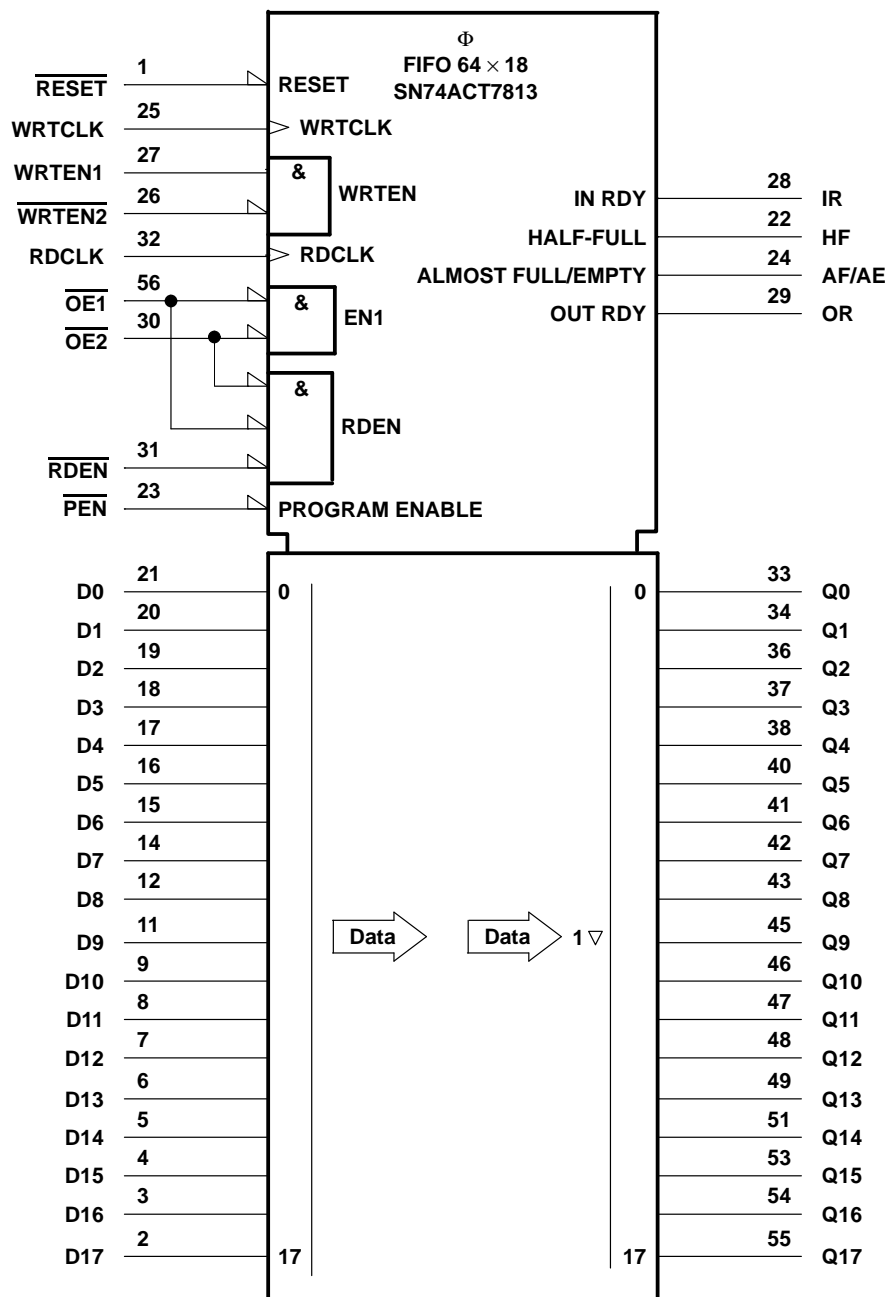
Copyright © 1992, Texas Instruments Incorporated

SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

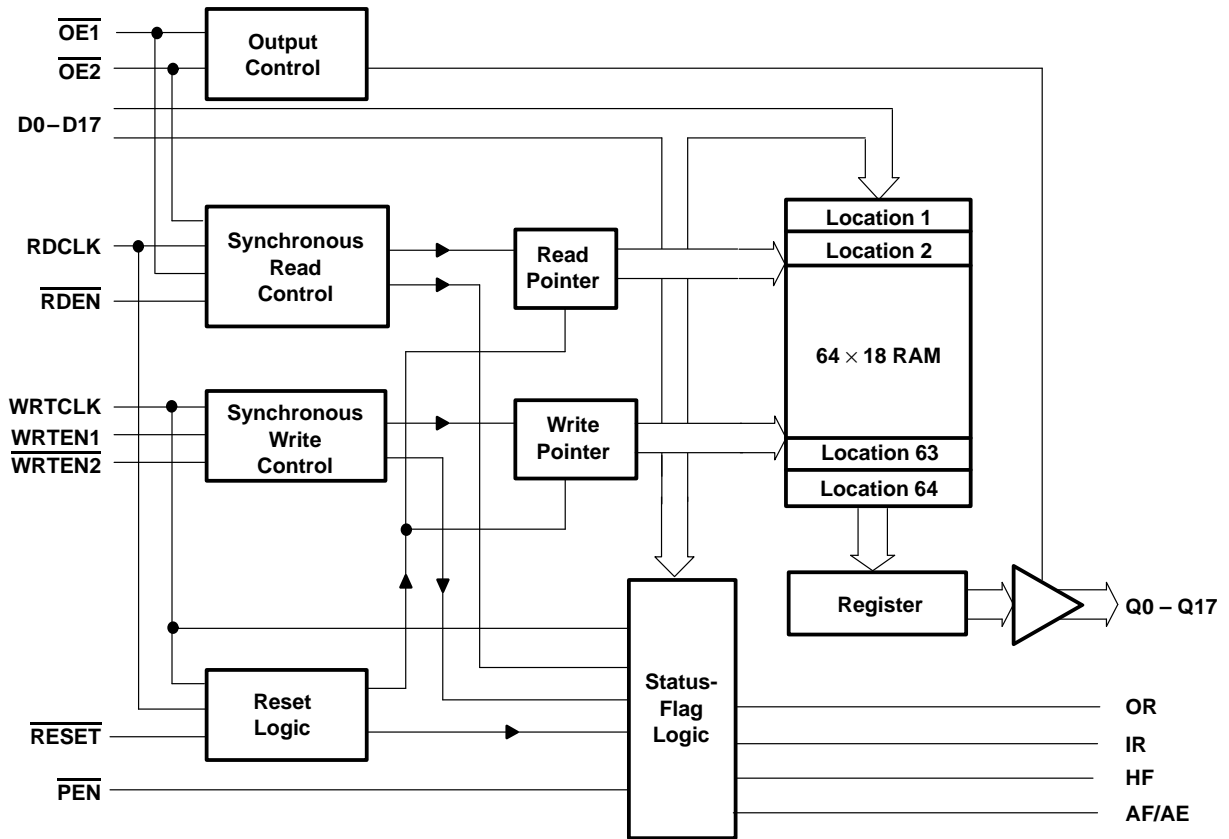
SCAS199 – JANUARY 1991 – REVISED APRIL 1992

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

functional block diagram



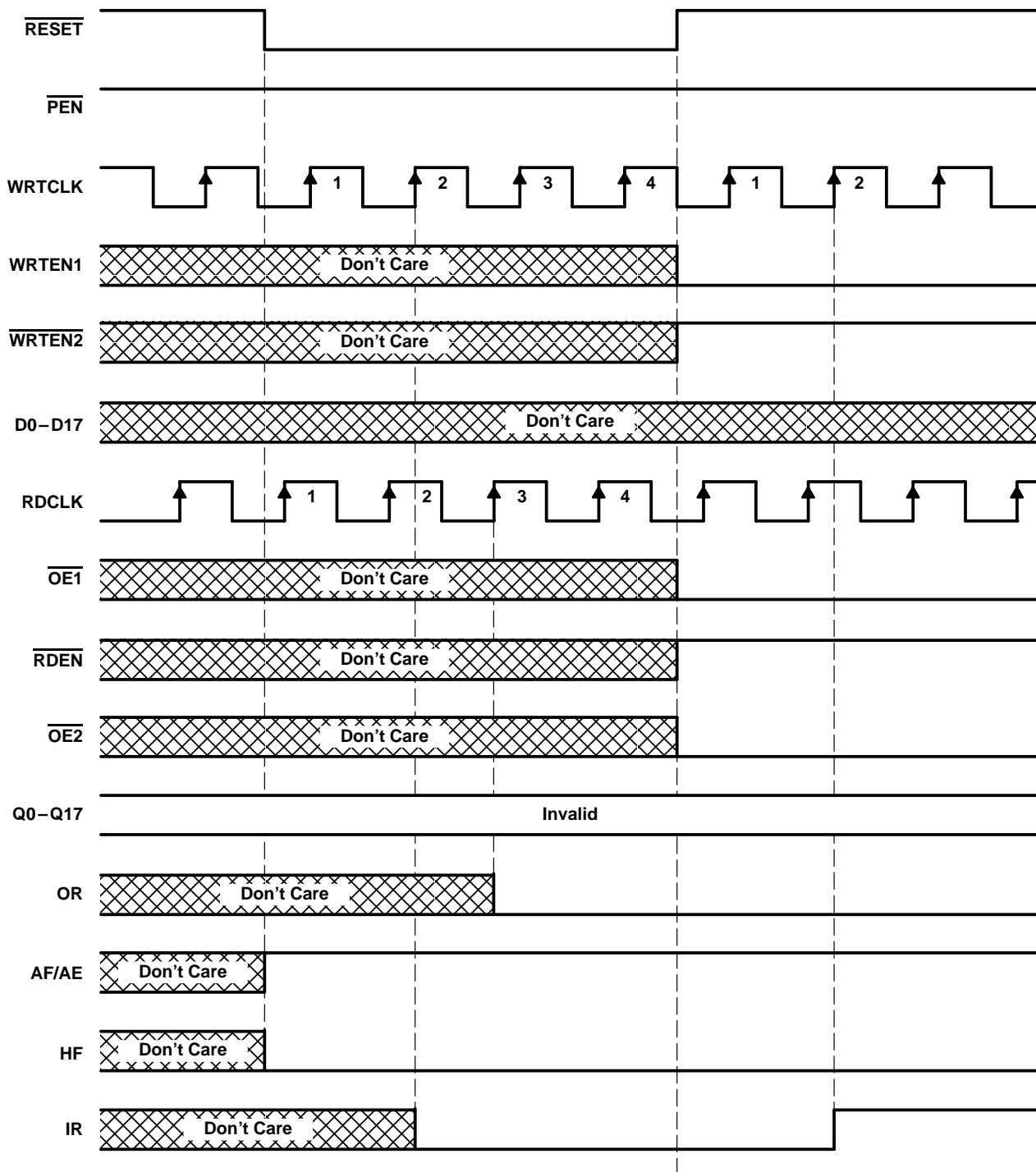
SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
AF/AE	24	O	Almost-full/almost-empty flag. Depth offset values can be programmed for AF/AE, or the default value of 8 can be used for both the almost-empty offset (X) and the almost-full offset (Y). AF/AE is high when memory contains X or less words or (64 – Y) or more words. AF/AE is high after reset.
D0–D17	21–14, 12–11, 9–2	I	The 18-bit data input port
HF	22	O	Half-full flag. HF is high when the FIFO memory contains 32 or more words. HF is low after reset.
IR	28	O	Input-ready flag. IR is synchronized to the low-to-high transition of WRTCLK. When IR is low, the FIFO is full and writes are disabled. IR is low during reset and goes high on the second low-to-high transition of WRTCLK after reset.
$\overline{\text{OE1}}$, $\overline{\text{OE2}}$	56, 30	I	Output enables. When $\overline{\text{OE1}}$, $\overline{\text{OE2}}$, and $\overline{\text{RDEN}}$ are low and OR is high, data is read from the FIFO on a low-to-high transition of RDCLK. When either $\overline{\text{OE1}}$ or $\overline{\text{OE2}}$ is high, reads are disabled and the data outputs are in the high-impedance state.
OR	29	O	Output-ready flag. OR is synchronized to the low-to-high transition of RDCLK. When OR is low, the FIFO is empty and reads are disabled. Ready data is present on Q0–Q17 when OR is high. OR is low during reset and goes high on the third low-to-high transition of RDCLK after the first word is loaded to empty memory.
$\overline{\text{PEN}}$	23	I	Program enable. After reset and before the first word is written to the FIFO, the binary value on D0–D4 is latched as an AF/AE offset value when $\overline{\text{PEN}}$ is low and WRTCLK is high.
Q0–Q17	33–34, 36–38, 40–43, 45–49, 51, 53–55	O	The 18-bit data output port. After the first valid write to empty memory, the first word is output on Q0–Q17 on the third rising edge of RDCLK. OR is also asserted high at this time to indicate ready data. When OR is low, the last word read from the FIFO is present on Q0–Q17.
RDCLK	32	I	Read clock. RDCLK is a continuous clock and can be asynchronous or coincident to WRTCLK. A low-to-high transition of RDCLK reads data from memory when $\overline{\text{OE1}}$, $\overline{\text{OE2}}$, and $\overline{\text{RDEN}}$ are low and OR is high. OR is synchronous to the low-to-high transition of RDCLK.
$\overline{\text{RDEN}}$	31	I	Read enable. When $\overline{\text{RDEN}}$, $\overline{\text{OE1}}$, and $\overline{\text{OE2}}$ are low and OR is high, data is read from the FIFO on the low-to-high transition of RDCLK.
$\overline{\text{RESET}}$	1	I	Reset. To reset the FIFO, four low-to-high transitions of RDCLK and four low-to-high transitions of WRTCLK must occur while $\overline{\text{RESET}}$ is low. This sets HF, IR, and OR low and AF/AE high.
WRTCLK	25	I	Write clock. WRTCLK is a continuous clock and can be asynchronous or coincident to RDCLK. A low-to-high transition of WRTCLK writes data to memory when $\overline{\text{WRTE2}}$ is low, $\overline{\text{WRTE1}}$ is high, and IR is high. IR is synchronous to the low-to-high transition of WRTCLK.
$\overline{\text{WRTE1}}$, $\overline{\text{WRTE2}}$	27, 26	I	Write enables. When $\overline{\text{WRTE1}}$ is high, $\overline{\text{WRTE2}}$ is low, and IR is high, data is written to the FIFO on a low-to-high transition of WRTCLK.



Define the AF/AE Flag Using
the Default Value of X = Y = 8

Figure 1. Reset Cycle

SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

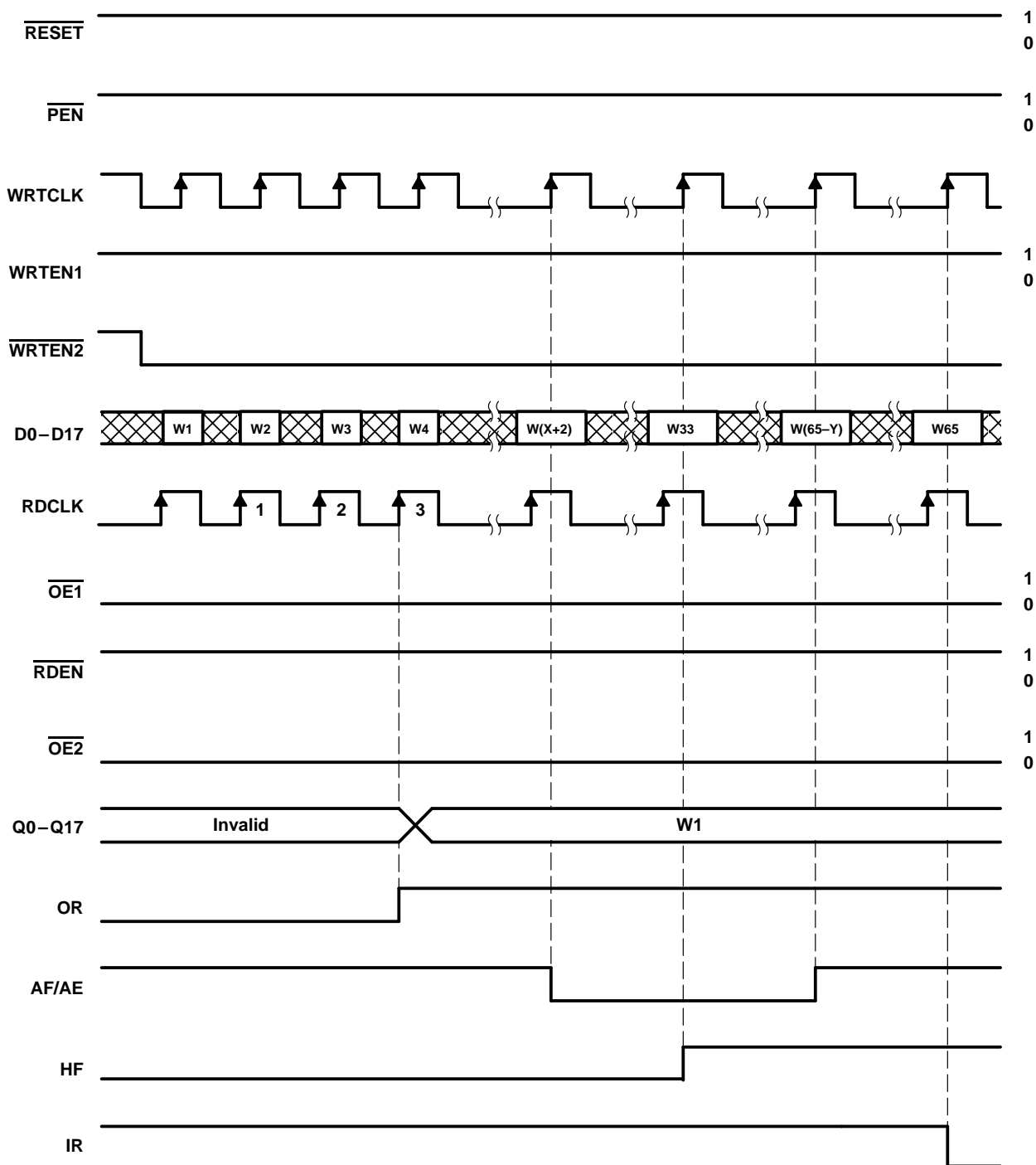


Figure 2. Write Cycle

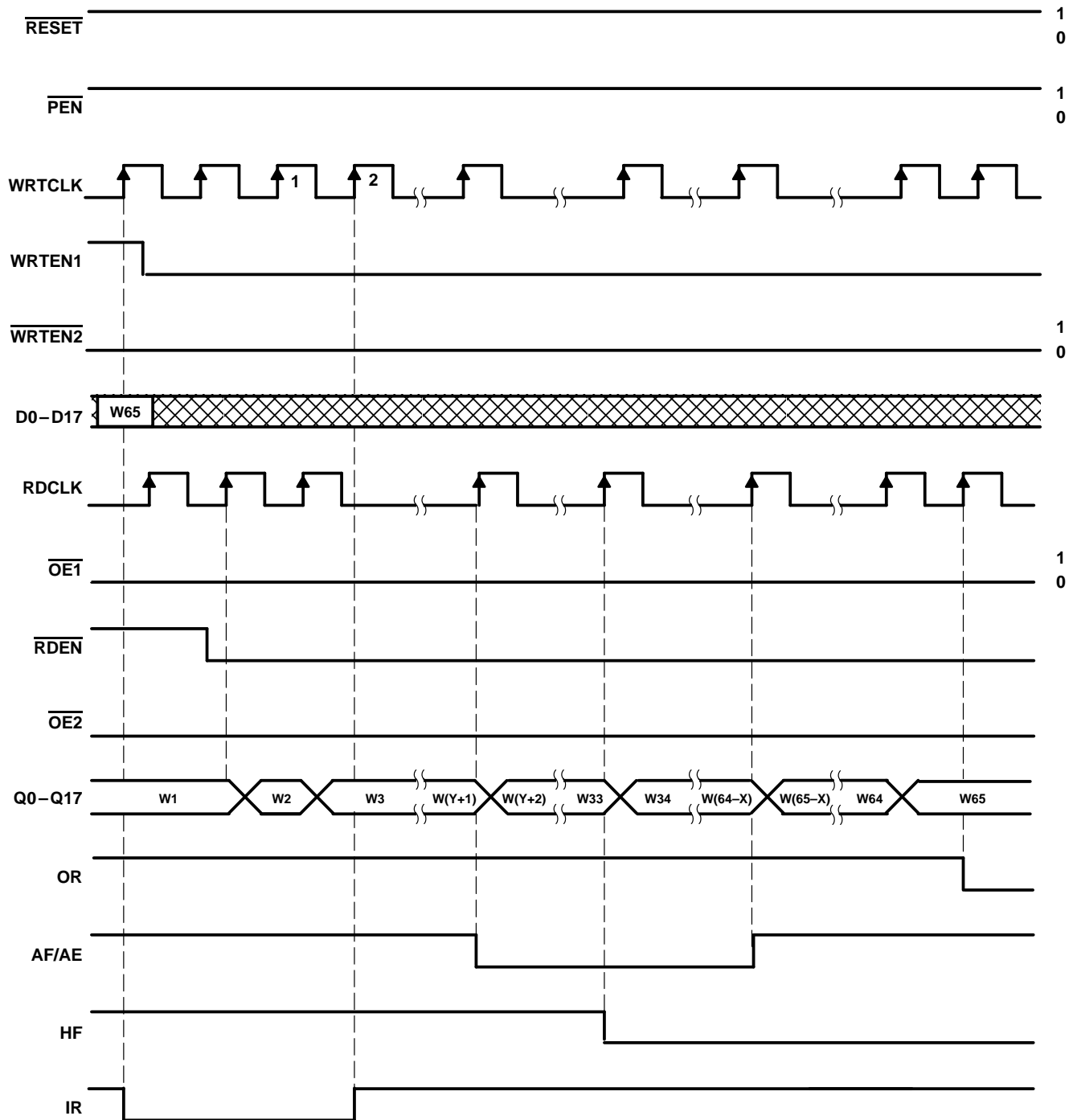


Figure 3. Read Cycle

SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

offset values for AF/AE

The almost-full/almost-empty flag has two programmable limits: the almost-empty offset value (X) and the almost-full offset value (Y). They can be programmed after the FIFO is reset and before the first word is written to memory. If the offsets are not programmed, the default values of $X = Y = 8$ are used. The AF/AE flag is high when the FIFO contains X or less words or $(64 - Y)$ or more words.

Program enable (\overline{PEN}) should be held high throughout the reset cycle. \overline{PEN} can be brought low only when IR is high and WRTCLK is low. On the following low-to-high transition of WRTCLK, the binary value on D0–D4 is stored as the almost-empty offset value (X) and the almost-full offset value (Y). Holding \overline{PEN} low for another low-to-high transition of WRTCLK reprograms Y to the binary value on D0–D4 at the time of the second WRTCLK low-to-high transition. When the offsets are being programmed, writes to the FIFO memory are disabled regardless of the state of the write enables (WRTEN1, WRTEN2). A maximum value of 31 can be programmed for either X or Y (see Figure 4). To use the default values of $X = Y = 8$, \overline{PEN} must be held high.

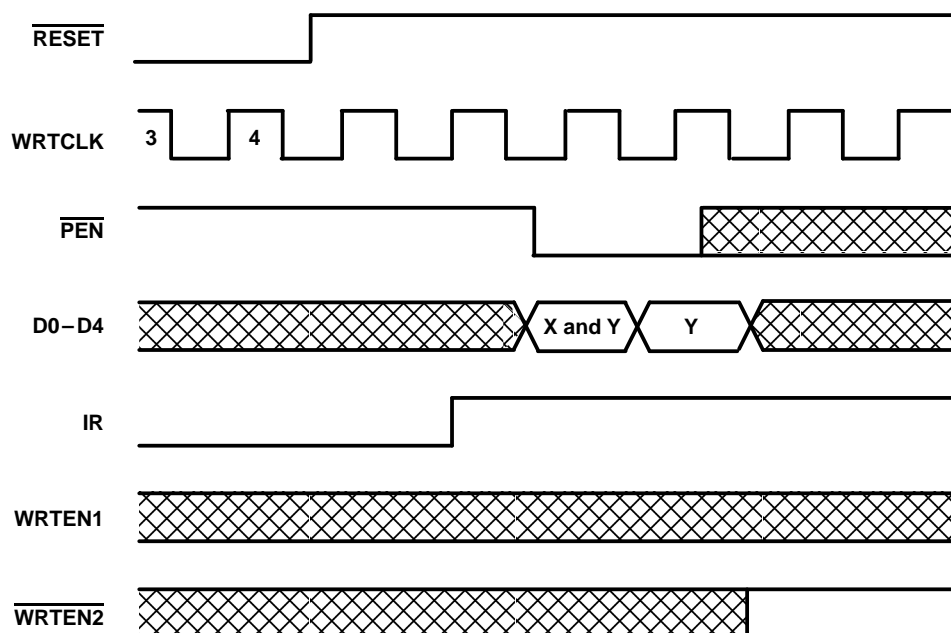


Figure 4. Programming X and Y Separately

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage, V_I	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

recommended operating conditions

			'ACT7813-15		'ACT7813-20		'ACT7813-25		'ACT7813-40		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		4.5	5.5	4.5	5.5	4.5	5.5	4.5	5.5	V
V _{IH}	High-level input voltage		2		2		2		2		V
V _{IL}	Low-level input voltage			0.8		0.8		0.8		0.8	V
I _{OH}	High-level output current	Q outputs, Flags		–8		–8		–8		–8	mA
I _{OL}	Low-level output current	Q outputs		16		16		16		16	mA
		Flags		8		8		8		8	
f _{clock}	Clock frequency			67		50		40		25	MHz
t _w	Pulse duration	WRTCLK high or low	6		7		8		12		ns
		RDCLK high or low	6		7		8		12		
		PEN low	8		9		9		12		
t _{su}	Setup time	D0–D17 before WRTCLK↑	4		5		5		5		ns
		WRTEN1, WRTEN2 before WRTCLK↑	4		5		5		5		
		OE1, OE2 before RDCLK↑	5		5		6		6		
		RDEN before RDCLK↑	4		5		5		5		
		Reset: RESET low before first WRTCLK↑ and RDCLK↑†	5		6		6		6		
		PEN before WRTCLK↑	5		6		6		6		
t _h	Hold time	D0–D17 after WRTCLK↑	0		0		0		0		ns
		WRTEN1, WRTEN2 after WRTCLK↑	0		0		0		0		
		OE1, OE2, RDEN after RDCLK↑	0		0		0		0		
		Reset: RESET low after fourth WRTCLK↑ and RDCLK↑†	2		2		2		2		
		PEN high after WRTCLK↓	0		0		0		0		
		PEN low after WRTCLK↑	2		2		2		2		
T _A	Operating free-air temperature		0	70	0	70	0	70	0	70	°C

† To permit the clock pulse to be utilized for reset purposes



SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V _{OH}	V _{CC} = 4.5 V, I _{OH} = – 8 mA	2.4			V
V _{OL}	Flags V _{CC} = 4.5 V, I _{OL} = 8 mA			0.5	V
	Q outputs V _{CC} = 4.5 V, I _{OL} = 16 mA			0.5	
I _I	V _{CC} = 5.5 V, V _I = V _{CC} or 0			±5	μA
I _{OZ}	V _{CC} = 5.5 V, V _O = V _{CC} or 0			±5	μA
I _{CC}	V _I = V _{CC} – 0.2 V or 0			400	μA
ΔI _{CC} ‡	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND			1	mA
C _i	V _I = 0, f = 1 MHz		4		pF
C _o	V _O = 0, f = 1 MHz		8		pF

† All typical values are at V_{CC} = 5 V, T_A = 25°C.

‡ This is the supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (see Figures 9 and 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	'ACT7813-15			'ACT7813-20		'ACT7813-25		'ACT7813-40		UNIT
			MIN	TYP†	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}	WRTCLK or RDCLK		67			50		40		25		MHz
t _{pd}	RDCLK↑	Any Q	4	9.5	12	4	13	4	15	4	20	ns
t _{pd} §				8.5								
t _{pd}	WRTCLK↑	IR	3		8.5	3	11	3	13	3	15	ns
t _{pd}	RDCLK↑	OR	3		8.5	3	11	3	13	3	15	ns
t _{pd}	WRTCLK↑	AF/AE	7		16.5	7	19	7	21	7	23	ns
	RDCLK↑		7		17	7	19	7	21	7	23	
t _{PLH}	WRTCLK↑	HF	7		15	7	17	7	19	7	21	ns
t _{PHL}	RDCLK↑		7		15.5	7	18	7	20	7	22	
t _{PLH}	RESET low	AF/AE	2		9	2	11	2	13	2	15	ns
t _{PHL}		HF	2		10	2	12	2	14	2	16	
t _{en}	OE1, OE2	Any Q	2		8.5	2	11	2	11	2	11	ns
t _{dis}			2		9.5	2	11	2	14	2	14	

§ This parameter is measured with a 30-pF load (see Figure 5).

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	Outputs enabled C _L = 50 pF, f = 5 MHz	53	pF



TYPICAL CHARACTERISTICS

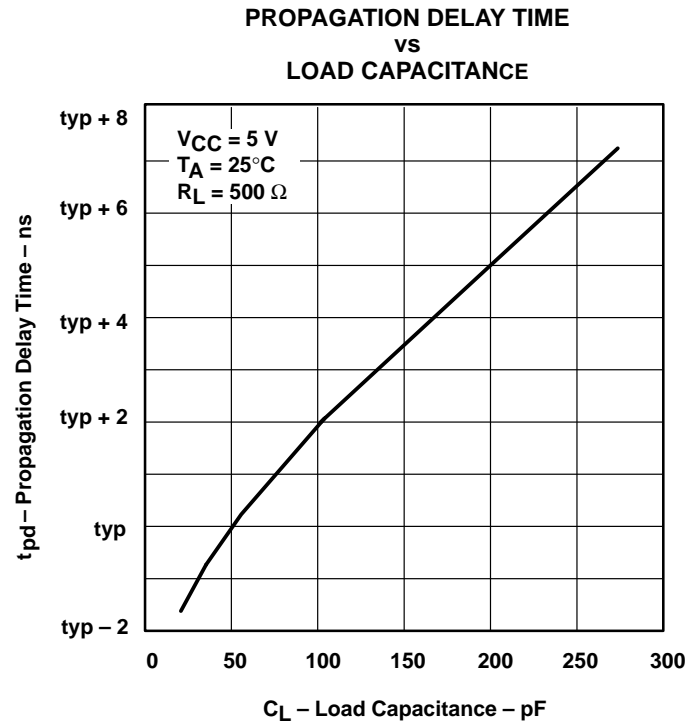


Figure 5

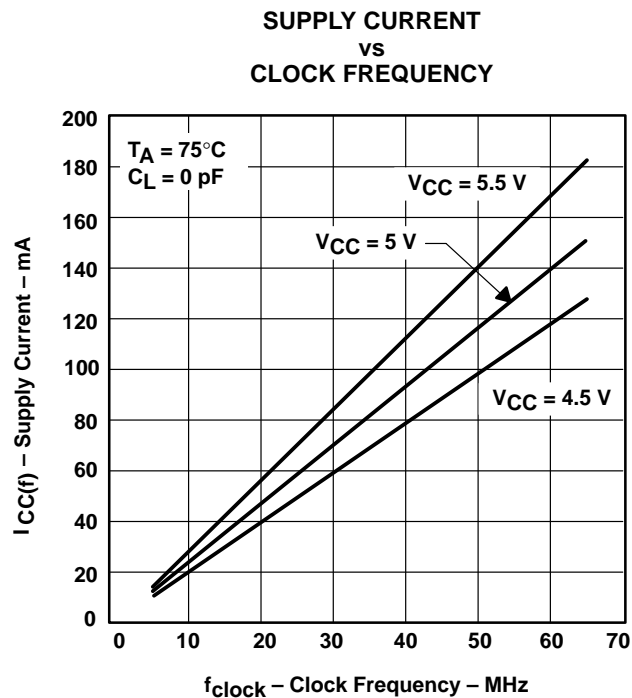


Figure 6

SN74ACT7813

64 × 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

TYPICAL CHARACTERISTICS

calculating power dissipation

With $I_{CC(f)}$ taken from Figure 6, the maximum power dissipation (P_T) based on all data outputs changing states on each read can be calculated using:

$$P_T = V_{CC} \times [I_{CC(f)} + (N \times \Delta I_{CC} \times dc)] + \Sigma(C_L \times V_{CC}^2 \times f_o)$$

A more accurate power calculation based on device use and average number of data outputs switching can be found using:

$$P_T = V_{CC} \times [I_{CC} + (N \times \Delta I_{CC} \times dc)] + \Sigma(C_{pd} \times V_{CC}^2 \times f_i) + \Sigma(C_L \times V_{CC}^2 \times f_o)$$

where:

- I_{CC} = power-down I_{CC} maximum
- N = number of inputs driven by a TTL device
- ΔI_{CC} = increase in supply current
- dc = duty cycle of inputs at a TTL high level of 3.4 V
- C_{pd} = power dissipation capacitance
- C_L = output capacitive load
- f_i = data input frequency
- f_o = data output frequency



The diagram shows the timing relationships for two SN74ACT7813 comparators. The top comparator has inputs WRTCLK, WRTEN1, WRTEN2, RDCLK, OE1, RDEN, and OE2. The bottom comparator has inputs RDCLK, OE1, RDEN, OE2, WRTCLK, WRTEN1, and WRTEN2. Both comparators have 18-bit data inputs (D0-D17) and 18-bit data outputs (Q0-Q17). The timing diagram shows the signals for CLOCK A, W/RA, CSA, CLOCK B, W/RB, CSB, and the data signals A0-A17, B0-B17, and Q0-Q17. The signals are shown as waveforms with specific timing points marked by dots and arrows.

The diagram illustrates a 36-bit parallel adder implemented using two SN74ACT7813 18-bit adders. The inputs are a 36-bit data bus D0-D35, a 36-bit output bus Q0-Q35, and control signals WRTCLK, WRTEN1, WRTEN2, RDCLK, RDEN, OE1, OE2, and IR. The adders are configured as follows:

- Top Adder (SN74ACT7813):**
 - Inputs:** WRTCLK, WRTEN1, WRTEN2, IR, and D0-D17 (from the 36-bit bus).
 - Outputs:** RDCLK, RDEN, OE1, OE2, OR, and Q0-Q17.
- Bottom Adder (SN74ACT7813):**
 - Inputs:** WRTCLK, WRTEN1, WRTEN2, IR, and D0-D17 (from the 36-bit bus).
 - Outputs:** RDCLK, RDEN, OE1, OE2, OR, and Q0-Q17.

The 36-bit data bus D0-D35 is split into two 18-bit segments, D0-D17 and D18-D35. The top adder takes D0-D17 as input and produces Q0-Q17. The bottom adder takes D18-D35 as input and produces Q18-Q35. The control signals WRTCLK, WRTEN1, WRTEN2, RDCLK, RDEN, OE1, OE2, and IR are connected to the corresponding pins of both adders. The output Q0-Q35 is the 36-bit result of the addition.

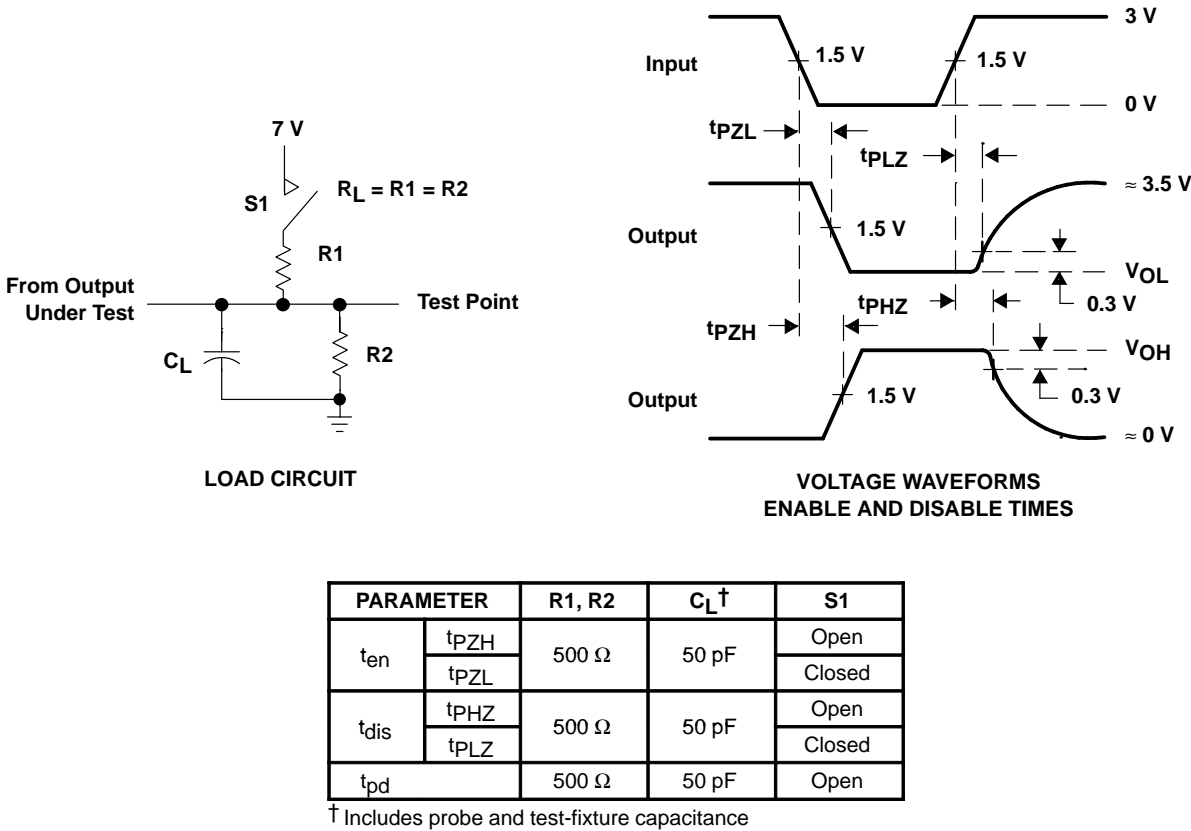
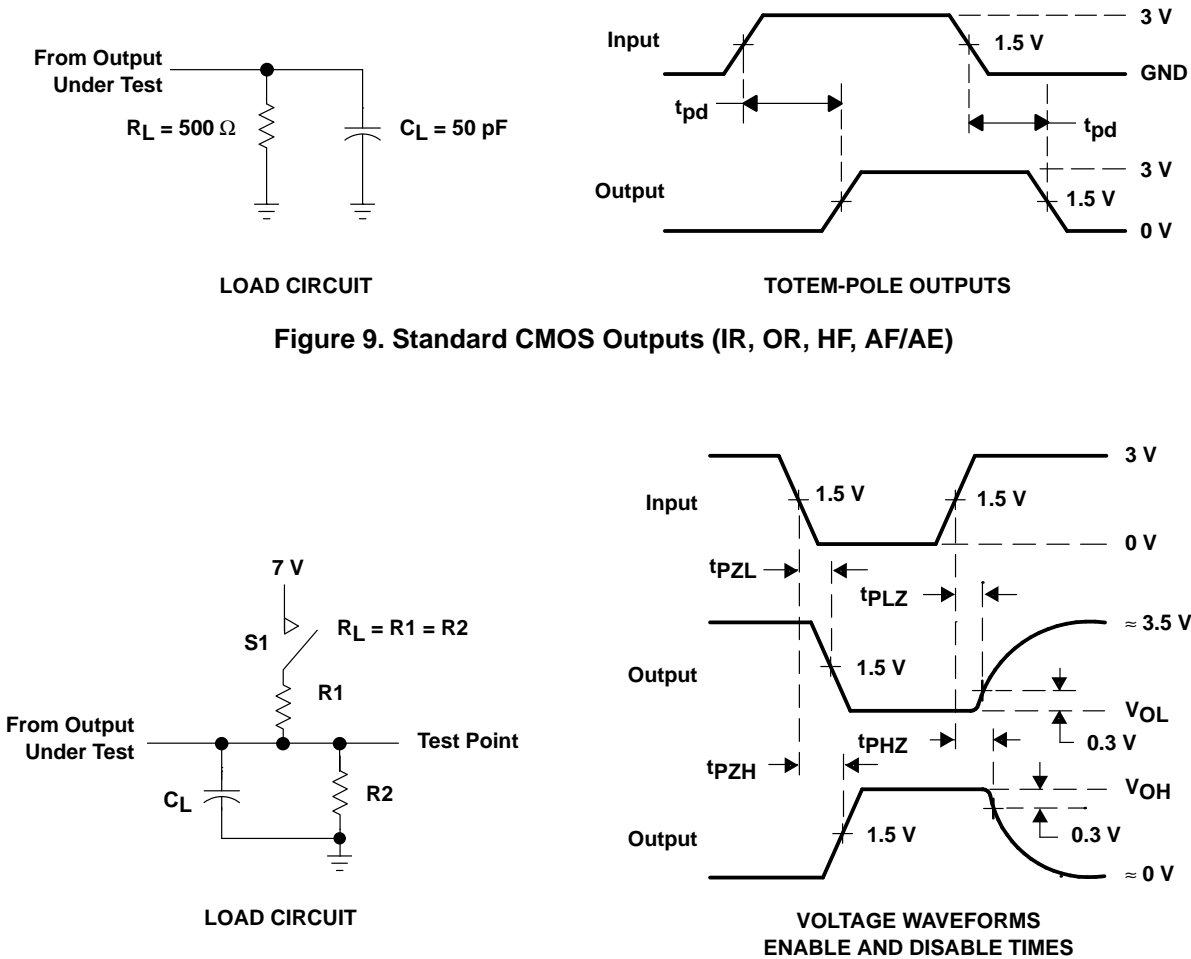


SN74ACT7813

64 × 18 Clocked First-In, First-Out Memory

SCAS199 – JANUARY 1991 – REVISED APRIL 1992

PARAMETER MEASUREMENT INFORMATION



IMPORTANT NOTICE

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.